



[WE1] Nano Devices Using 2D Materials I	
Date / Time	July 25 (Wed.), 2018 / 09:00-10:30
Place	Room E (#107~108)
Session Chair(s)	Myung-Ho Bae (KRISS, Korea)

WE1-1 [Invited] 09:00-09:30

Reconfigurable 2D Devices for Artificial Neural Network Applications

Ji-Ung Lee

SUNY Polytechnic Inst., USA

WE1-2 [Invited] 09:30-10:00

Electrically Tunable 2D Devices with Exceptional Functions

Gwan-Hyoung Lee

Yonsei Univ., Korea

WE1-3 [Invited] 10:00-10:30

Electrolyte-Gated Flexible Graphene Schottky Barrier Transistors

Jeong Ho Cho

Sungkyunkwan Univ., Korea